

CD54HC40105, CD74HC40105, CD54HCT40105

Data sheet acquired from Harris Semiconductor SCHS222C

February 1998 - Revised October 2003

High-Speed CMOS Logic 4-Bit x 16-Word FIFO Register

Features

- Independent Asynchronous Inputs and Outputs
- Expandable in Either Direction
- · Reset Capability
- · Status Indicators on Inputs and Outputs
- · Three-State Outputs
- Shift-Out Independent of Three-State Control
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N $_{IL}$ = 30%, N $_{IH}$ = 30% of V $_{CC}$ at V $_{CC}$ = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, I $_I \leq 1 \mu A$ at $V_{OL},\,V_{OH}$

Applications

- Bit-Rate Smoothing
- CPU/Terminal Buffering
- Data Communications
- · Peripheral Buffering
- Line Printer Input Buffers
- Auto-Dialers
- CRT Buffer Memories
- · Radar Data Acquisition

Description

The 'HC40105 and 'HCT40105 are high-speed silicon-gate CMOS devices that are compatible, except for "shift-out" circuitry, with the CD40105B. They are low-power first-in-out (FIFO) "elastic" storage registers that can store 16 four-bit words. The 40105 is capable of handling input and output data at different shifting rates. This feature makes it particularly useful as a buffer between asynchronous systems.

Each work position in the register is clocked by a control flipflop, which stores a marker bit. A "1" signifies that the position's data is filled and a "0" denotes a vacancy in that position. The control flip-flop detects the state of the preceding flip-flop and communicates its own status to the succeeding flip-flop. When a control flip-flop is in the "0" state and sees a "1" in the preceeding flip-flop, it generates a clock pulse that transfers data from the preceding four data latches into its own four data latches and resets the preceding flip-flop to "0". The first and last control flip-flops have buffered outputs. Since all empty locations "bubble" automatically to the input end, and all valid data ripple through to the output end, the status of the first control flip-flop (DATA-IN READY) indicates if the FIFO is full, and the status of the last flip-flop (DATA-OUT READY) indicates if the FIFO contains data. As the earliest data are removed from the bottom of the data stack (the output end), all data entered later will automatically propagate (ripple) toward the output.

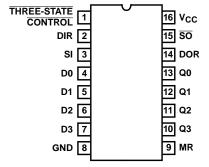
Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC40105F3A	-55 to 125	16 Ld CERDIP
CD54HCT40105F3A	-55 to 125	16 Ld CERDIP
CD74HC40105E	-55 to 125	16 Ld PDIP
CD74HC40105M	-55 to 125	16 Ld SOIC
CD74HC40105MT	-55 to 125	16 Ld SOIC
CD74HC40105M96	-55 to 125	16 Ld SOIC
CD74HCT40105E	-55 to 125	16 Ld PDIP
CD74HCT40105M	-55 to 125	16 Ld SOIC
CD74HCT40105MT	-55 to 125	16 Ld SOIC
CD74HCT40105M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

Pinout

CD54HC40105, CD54HCT40105 (CERDIP) CD74HC40105, CD74HCT40105 (PDIP, SOIC) TOP VIEW



Loading Data

Data can be entered whenever the DATA-IN READY (DIR) flag is high, by a low to high transition on the SHIFT-IN (SI) input. This input must go low momentarily before the next word is accepted by the FIFO. The DIR flag will go low momentarily, until the data have been transferred to the second location. The flag will remain low when all 16-word locations are filled with valid data, and further pulses on the SI input will be ignored until DIR goes high.

Unloading Data

As soon as the first word has rippled to the output, the data-out ready output (DOR) goes HIGH and data of the first word is available on the outputs. Data of other words can be removed by a negative-going transition on the shift-out input (\overline{SO}) . This negative-going transition causes the DOR signal to go LOW while the next word moves to the output. As long as valid data is available in the FIFO, the DOR signal will go high again, signifying that the next word is ready at the output. When the FIFO is empty, DOR will remain LOW, and any further commands will be ignored until a "1" marker ripples down to the last control register and DOR goes HIGH. If during unloading SI is HIGH, (FIFO is full) data on the data input of the FIFO is entered in the first location.

Master Reset

A high on the MASTER RESET (MR) sets all the control logic marker bits to "0". DOR goes low and DIR goes high. The contents of the data register are not changed, only declared invalid, and will be superseded when the first word is loaded. Thus, MR does not clear data within the register but only the control logic. If the shift-in flag (SI) is HIGH during the master reset pulse, data present at the input (D0 to D3) are immediately moved into the first location upon completion of the reset process.

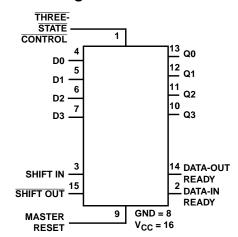
Three-State Outputs

In order to facilitate data busing, three-state outputs (Q0 to Q3) are provided on the data output lines, while the load condition of the register can be detected by the state of the DOR output. A HIGH on the three-state control flag (output enable input OE) forces the outputs into the high-impedance OFF-state mode. Note that the shift-out signal, unlike that in the CD40105B, is independent of the three-state output control. In the CD40105B, the three-state control must not be shifted from High to Low when the shift-out signal is Low (data loss would occur). In the high-speed CMOS version this restriction has been eliminated.

Cascading

The 40105 can be cascaded to form longer registers simply by connecting the DIR to SO and DOR to SI. In the cascaded mode, a MASTER RESET pulse must be applied after the supply voltage is turned on. For words wider than four bits, the DIR and the DOR outputs must be gated together with AND gates. Their outputs drive the SI and SO inputs in parallel, if expanding is done in both directions (see Figures 12 and 13).

Functional Diagram



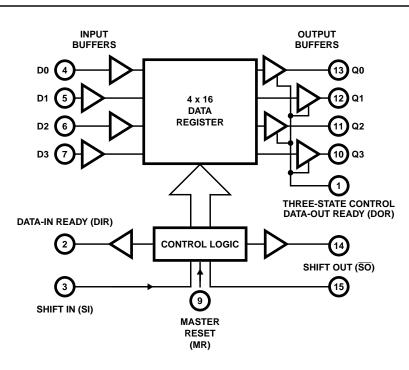
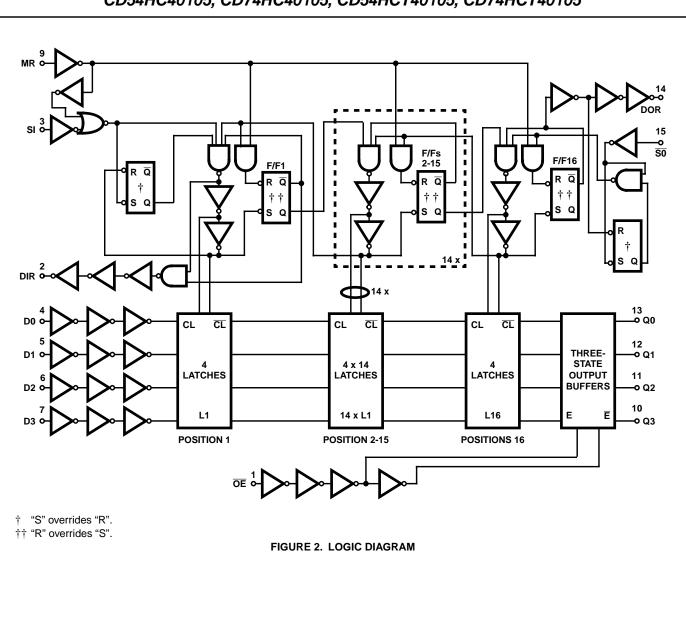


FIGURE 1. FUNCTIONAL BLOCK DIAGRAM



Absolute Maximum Ratings

DC Supply Voltage, V _{CC} 0.5V to 7V
DC Input Diode Current, I _{IK}
For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$
DC Output Diode Current, I _{OK}
For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC}

Thermal Information

Thermal Resistance (Typical, Note 1)	θ_{JA} (°C/W)
E (PDIP) Package	. 67
M (SOIC) Package	. 73
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range	-65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range (T _A)55 ⁰ C to 125 ⁰	C,
Supply Voltage Range, V _{CC}	
HC Types2V to 6	۷
HCT Types	ί۷
DC Input or Output Voltage, V _I , V _O 0V to V _C	СС
Input Rise and Fall Time	
2V	x)
4.5V 500ns (Ma	x)
6V	x)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TE: CONDI		V _{CC}	25°C			-40°C 1	O 85°C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	VoH	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
OWOO LOAGS			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
TTE LOGUS			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
OWIGO Edads			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
I I L Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	IĮ	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	lcc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μΑ

DC Electrical Specifications (Continued)

		TES CONDI		Vcc		25°C		-40°C 1	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Three-State Leakage Current	l _{OZ}	V _{IL} or V _{IH}	V _O = V _{CC} or GND	6	-	-	±0.5	-	±5	-	±10	μΑ
HCT TYPES	•							-				
High Level Input Voltage	V _{IH}	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{ОН}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μΑ
Three-State Leakage Current	l _{OZ}	V _{IL} or V _{IH}	V _O = V _{CC} or GND	5.5	-	-	±0.5	-	±5	-	±10	μΑ
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
ŌĒ	0.75
SI, SO	0.4
Dn	0.3
MR	1.5

NOTE: Unit Load is $\Delta I_{\hbox{CC}}$ limit specified in DC Electrical Table, e.g., 360µA max at 25°C.

^{2.} For dual-supply systems theoretical worst case ($V_I = 2.4V$, $V_{CC} = 5.5V$) specification is 1.8mA.

Prerequisite for Switching Specifications

			25	°C	-40°C 1	ГО 85 ⁰ С	-55°C T]	
PARAMETER	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES		•		•	•	•	•		•
SI Pulse Width	t _W	2	80	-	100	-	120	-	ns
HIGH or LOW		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
SO Pulse Width	t _W	2	120	-	150	-	180	-	ns
HIGH or LOW		4.5	24	-	30	-	36	-	ns
		6	20	-	26	-	31	-	ns
DIR Pulse Width	t _W	2	200	-	250	-	300	-	ns
HIGH or LOW		4.5	40	-	50	-	60	-	ns
		6	34	-	43	-	51	-	ns
DOR Pulse Width	t _W	2	200	-	250	-	300	-	ns
HIGH or LOW		4.5	40	-	50	-	60	-	ns
		6	34	-	43	-	51	-	ns
MR Pulse Width HIGH	t _W	2	120	-	150	-	180	-	ns
		4.5	24	-	30	-	36	-	ns
		6	20	-	26	-	31	-	ns
Removal Time	t _{REM}	2	50	-	65	-	75	-	ns
MR to SI		4.5	10	-	13	-	15	-	ns
		6	9	-	11	-	13	-	ns
Set-Up Time Dn to SI	tsu	2	5	-	5	-	5	-	ns
		4.5	5	-	5	-	5	-	ns
		6	5	-	5	-	5	-	ns
Hold Time	t _H	2	125	-	155	-	190	-	ns
Dn to SI		4.5	25	-	31	-	38	-	ns
		6	21	-	26	-	32	-	ns
Maximum Pulse Frequency	f _{MAX}	2	3	-	2	-	2	-	MHz
SI, SO		4.5	15	-	12	-	10	-	MHz
		6	18	-	14	-	12	-	MHz
HCT TYPES				•					1
SI Pulse Width HIGH or LOW	t _W	4.5	16	-	20	-	24	-	ns
SO Pulse Width HIGH or LOW	t _W	4.5	16	-	20	-	24	-	ns
DIR Pulse Width HIGH or LOW	t _W	4.5	40	-	50	-	60	-	ns
DOR Pulse Width HIGH or LOW	t _W	4.5	40	-	50	-	60	-	ns
MR Pulse Width HIGH	t _W	4.5	24	-	30	-	36	-	ns
Removal Time MR to SI	t _{REM}	4.5	15	-	19	-	22	-	ns
Set-Up Time Dn to SI	tsu	4.5	0	-	0	-	0	-	ns
Hold Time Dn to SI	t _H	4.5	25	-	31	-	38	-	ns
Maximum Pulse Frequency SI, SO	f _{MAX}	4.5	15	-	12	-	10	-	MHz

Switching Specifications Input t_{r} , $t_{f} = 6ns$

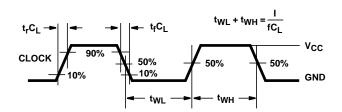
		TEST	v _{cc}	25°C			-40°C 1	го 85 ^о С	-55°C TO 125°C			
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
HC TYPES				•	•	•		•	•	•	1	
Propagation Delay	t _{PHL} ,	C _L = 50pF	2	-	-	175	-	220	-	265	ns	
MR to DIR, DOR	^t PLH	C _L = 50pF	4.5	-	-	35	-	44	-	53	ns	
		C _L = 15pF	5	-	15	-	-	-	-	-	ns	
		C _L = 50pF	6	-	-	30	-	37	-	45	ns	
SI to DIR	t _{PHL} ,	C _L = 50pF	2	-	-	210	-	265	-	315	ns	
	^t PLH	C _L = 50pF	4.5	-	-	42	-	53	-	63	ns	
		C _L = 15pF	5	-	18	-	-	-	-	-	ns	
		C _L = 50pF	6	-	-	36	-	45	-	54	ns	
SO to DOR	t _{PHL,}	C _L = 50pF	2	-	-	210	-	265	-	315	ns	
	t _{PLH}	C _L = 50pF	4.5	-	-	42	-	53	-	63	ns	
		C _L = 15pF	5	-	18	-	-	-	-	-	ns	
		C _L = 50pF	6	-	-	36	-	45	-	54	ns	
SO to Qn	t _{PHL,}	C _L = 50pF	2	-	-	400	-	500	-	600	ns	
	tPLH	C _L = 50pF	4.5	-	-	80	-	100	-	120	ns	
		C _L = 15pF	5	-	35	-	-	-	-	-	ns	
		C _L = 50pF	6	-	-	68	-	85	-	102	ns	
Propagation Delay/Ripple thru Delay SI to DOR	t _{PLH}	C _L = 50pF	2	-	-	2000	-	2500	-	3000	ns	
			4.5	-	-	400	-	500	-	600	ns	
			6	-	-	340	-	425	-	510	ns	
Propagation Delay/Ripple thru	t _{PLH}	C _L = 50pF	2	-	-	2500	-	3125	-	3750	ns	
Delay SO to DIR			4.5	-	-	500	-	625	-	750	ns	
			6	-	-	425	-	532	-	638	ns	
Propagation Delay/Ripple thru	t _{PLH}	C _L = 50pF	2	-	-	1500	-	1900	-	2250	ns	
Delay SI to Qn			4.5	-	-	300	-	380	-	450	ns	
			6	-	-	260	-	330	-	380	ns	
Three-State Output Enable	t _{PZH} , t _{PZL}	C _L = 50pF	2	-	-	150	-	190	-	225	ns	
ŌĒ to Q _n			4.5	-	-	30	-	38	-	45	ns	
			6	-	-	26	-	33	-	38	ns	
Three-State Output Disable	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	-	140	-	175	-	210	ns	
OE to Qn		C _L = 50pF	4.5	-	-	28	-	35	-	42	ns	
		C _L = 50pF	6	-	-	24	-	30	-	36	ns	
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns	
			4.5	-	-	15	-	19	-	22	ns	
			6	-	-	13	-	16	-	19	ns	
Maximum SI, SO Frequency	f _{MAX}	C _L = 15pF	5	-	32	-	-	-	-	-	MHz	
Input Capacitance	C _{IN}	C _L = 50pF	-	-	-	10	-	10	-	10	pF	
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	C _L = 15pF	5	-	83	-	-	-	-	-	pF	

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST CONDITIONS	V _{CC}	25°C			-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL		(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS	
Three-State Output Capacitance	c _o	C _L = 50pF	-	-	-	15	-	15	-	15	pF	
HCT TYPES										-		
Propagation Delay Time	t _{PLH} ,	C _L = 50pF	4.5	-	-	36	-	45	-	54	ns	
MR to DIR, DOR	tPHL	C _L = 15pF	5	-	15	-	-	-	-	-	ns	
SI to DIR	t _{PLH,}	C _L = 50pF	4.5	-	-	42	-	53	-	63	ns	
	t _{PHL}	C _L =15pF	5	-	18	-	-	-	-	-	ns	
SO to DOR	t _{PLH,}	C _L = 50pF	4.5	-	-	42	-	53	-	63	ns	
	tPHL	C _L =15pF	5	-	18	-	-	-	-	-	ns	
SO to Qn	t _{PLH} ,	C _L = 50pF	4.5	-	-	80	-	100	-	120	ns	
	tPHL	C _L =15pF	5	-	35	-	-	-	-	-	ns	
Propagation Delay/Ripple thru Delay SI to DOR	^t PLH	C _L = 50pF	4.5	-	-	400	-	500	-	600	ns	
Propagation Delay/Ripple thru Delay SO to DIR	^t PLH	C _L = 50pF	4.5	-	-	500	-	625	-	750	ns	
Propagation Delay/Ripple thru Delay SI to Qn	^t PLH	C _L = 50pF	4.5	-	-	300	-	380	-	450	ns	
Three-State Output Enable OE to Q _n	t _{PZH} , t _{PZL}	C _L = 50pF	4.5	-	-	35	-	44	-	53	ns	
Three-State Output Disable OE to Qn	t _{PHZ} , t _{PLZ}	C _L = 50pF	4.5	-	-	30	-	38	-	45	ns	
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	19	-	22	ns	
Maximum CP Frequency	f _{MAX}	C _L =15pF	5	-	32	-	-	-	-	-	MHz	
Input Capacitance	C _{IN}	C _L = 50pF	-	-	-	10	-	10	-	10	pF	
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	C _L =15pF	5	-	83	-	-	-	-	-	pF	
Three-State Output Capacitance	CO	C _L = 50pF	-	-	-	15	-	15	-	15	pF	

C_{PD} is used to determine the dynamic power consumption, per package.
 P_D = C_{PD} V_{CC}² f_i + Σ (C_L V_{CC}² f₀) where f_i = Input Frequency, f₀ = Output Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 3. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

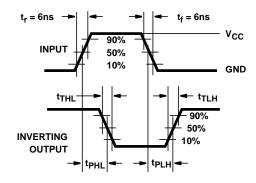
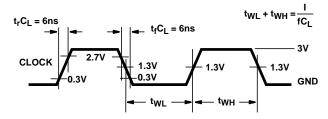


FIGURE 5. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 4. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

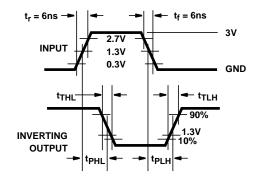
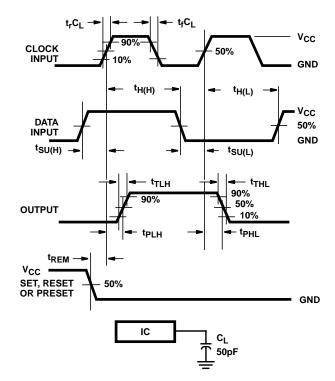


FIGURE 6. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

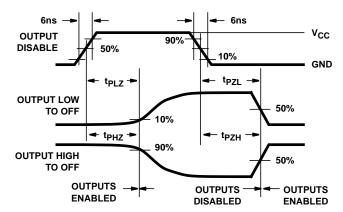
Test Circuits and Waveforms (Continued)



3V CLOCK **INPUT** 0.3V **GND** t_{H(H)} t_{H(L)} 3V DATA 1.3V 1.3V **INPUT** GND tSU(L) tSU(H) t_{TLH} - t_{THL} 90% 90% OUTPUT .3V 10% t_{PHL} ^tREM **3V** SET, RESET **OR PRESET** GND IC $\textbf{C}_{\textbf{L}}$ 50pF

FIGURE 7. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

FIGURE 8. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS



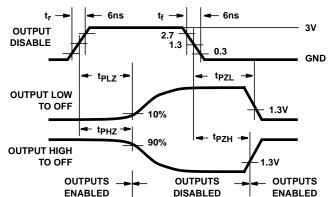
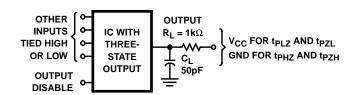


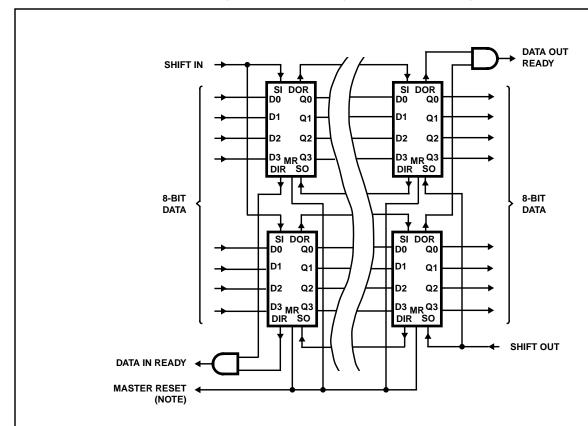
FIGURE 9. HC THREE-STATE PROPAGATION DELAY WAVEFORM

FIGURE 10. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



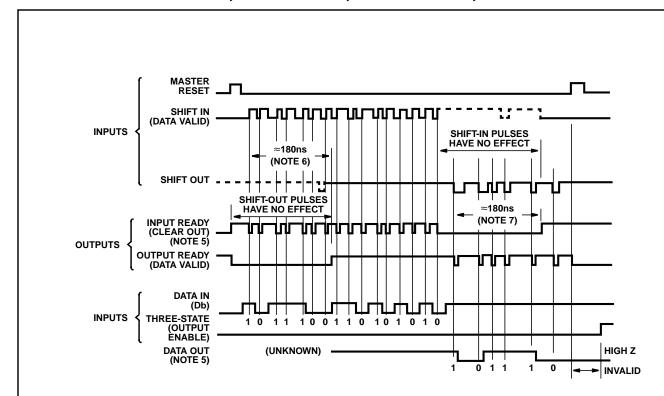
NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 11. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT



NOTE: Pulse must be applied for cascading by 16 N bits.

FIGURE 12. EXPANSION, 8-BITS WIDE BY 16 N-BITS LONG USING HC/HCT40105



- 5. Data valid goes to high level in advance of the data out by a maximum of 38ns at $V_{CC} = 4.5V$ for $C_L = 50pF$ and $T_A = 25^{\circ}C$.
- 6. At $V_{CC} = 4.5V$, ripple time from position 1 to position 16.
- 7. At V_{CC} = 4.5V, ripple time from position 16 to position 1.

FIGURE 13. TIMING DIAGRAM FOR THE CD74HC/HCT40105







PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD54HC40105F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT40105F3A	ACTIVE	CDIP	J	16	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC40105E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC40105EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC40105M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC40105M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC40105M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC40105M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC40105ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC40105MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC40105MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC40105MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC40105MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT40105EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT40105M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105MTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT40105MTG4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows: **ACTIVE:** Product device recommended for new designs. **LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.



PACKAGE OPTION ADDENDUM

23-Apr-2007

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

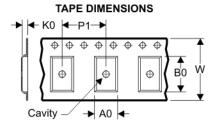
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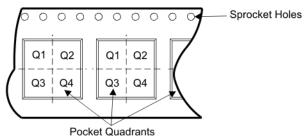
TAPE AND REEL BOX INFORMATION

REEL DIMENSIONS Reel Diameter Reel Width



	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
Р	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC40105M96	D	16	SITE 27	330	16	6.5	10.3	2.1	8	16	Q1
CD74HCT40105M96	D	16	SITE 27	330	16	6.5	10.3	2.1	8	16	Q1





Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)	
CD74HC40105M96	D	16	SITE 27	342.9	336.6	0.0	
CD74HCT40105M96	D	16	SITE 27	342.9	336.6	0.0	

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AC.



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